BLF8G20LS-400PV; BLF8G20LS-400PGV Power LDMOS transistor

AMPLEON

Rev. 5 — 1 September 2015

Product data sheet

Product profile

1.1 General description

400 W LDMOS power transistor with improved video bandwidth for base station applications at frequencies from 1805 MHz to 1995 MHz.

Table 1. Typical performance

Typical RF performance at T_{case} = 25 °C in a common source class-AB production test circuit, tested on straight lead device.

| Test signal | f | I _{Dq} | V _{DS} | P _{L(AV)} | Gp | η_D | ACPR _{5M} |
|------------------|--------------|-----------------|-----------------|--------------------|------|----------|--------------------|
| | (MHz) | (mA) | (V) | (W) | (dB) | (%) | (dBc) |
| 2-carrier W-CDMA | 1805 to 1995 | 3400 | 28 | 95 | 19 | 28 | -33 <u>[1]</u> |

^[1] Test signal: 3GPP test model 1; 64 DPCH; PAR = 7.5 dB at 0.01 % probability on CCDF; carrier spacing = 5 MHz; f_1 = 1807.5 MHz; f_2 = 1812.5 MHz; f_3 = 1872.5 MHz; f_4 = 1877.5 MHz.

1.2 Features and benefits

- Decoupling leads to enable improved Video BandWidth (VBW) (120 MHz typical)
- High efficiency
- Low thermal resistance providing excellent thermal stability
- Designed for broadband operation
- Lower output capacitance for improved performance in Doherty applications
- Designed for low memory effects providing excellent pre-distortability
- Internally matched for ease of use
- Integrated ESD protection
- Design optimized for gull-wing
- Excellent ruggedness
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)

1.3 Applications

RF power amplifiers for base stations and multi carrier applications in the 1805 MHz to 1995 MHz frequency range

2. Pinning information

Table 2. Pinning

| Table 2. | Pinning | | |
|----------|----------------------|-----------------------|----------------|
| Pin | Description | Simplified outline | Graphic symbol |
| BLF8G20 | LS-400PV (SOT1242B) | | |
| 1 | drain1 | 0 4 0 7 | |
| 2 | drain2 | 6 1 2 7 | 6 |
| 3 | gate1 | | 8•- |
| 4 | gate2 | | 3——5 |
| 5 | source | [1] 8 3 4 9 | 4——5 |
| 6 | decoupling1 | 5 | 9 • |
| 7 | decoupling2 | | 7 |
| 8 | n.c. | | aaa-007816 |
| 9 | n.c. | | |
| BLF8G20 | LS-400PGV (SOT1242C) | , | " |
| 1 | drain1 | | |
| 2 | drain2 | 6 1 2 7 | 1 6 |
| 3 | gate1 | | 8 - - |
| 4 | gate2 | 8 3 4 9 | 3—— |
| 5 | source | <u>[1]</u> 8 3 4 9 5 | 4 |
| 6 | decoupling1 | | 9 ← |
| 7 | decoupling2 | | 7 |
| 8 | n.c. | | aaa-007816 |
| 9 | n.c. | | |

^[1] Connected to flange.

3. Ordering information

Table 3. Ordering information

| Type number | Packag | Package | | | |
|------------------|--|--|----------|--|--|
| | Name | ame Description Vers | | | |
| BLF8G20LS-400PV | - earless flanged ceramic package; 8 leads | | SOT1242B | | |
| BLF8G20LS-400PGV | - | earless flanged ceramic package; 8 leads SOT | | | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|------------|------|------|------|
| V_{DS} | drain-source voltage | | - | 65 | V |
| V_{GS} | gate-source voltage | | -0.5 | +13 | V |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | [1] | - | 225 | °C |

^[1] Continuous use at maximum temperature will affect the reliability, for details refer to the on-line MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------------|--|--|------|------|
| R _{th(j-c)} | thermal resistance from junction to case | T _{case} = 80 °C; P _L = 80 W | 0.23 | K/W |

6. Characteristics

Table 6. DC characteristics

 $T_j = 25$ °C; per section unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|---------------------|----------------------------------|--|-----|-------|-----|------|
| $V_{(BR)DSS}$ | drain-source breakdown voltage | $V_{GS} = 0 \text{ V}; I_D = 3.0 \text{ mA}$ | 65 | - | - | V |
| $V_{GS(th)}$ | gate-source threshold voltage | V_{DS} = 10 V; I_{D} = 300 mA | 1.5 | 1.9 | 2.3 | ٧ |
| I _{DSS} | drain leakage current | V _{GS} = 0 V; V _{DS} = 28 V | - | - | 3.0 | μΑ |
| I _{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 3.75 \text{ V};$ $V_{DS} = 10 \text{ V}$ | | 51.5 | - | Α |
| I _{GSS} | gate leakage current | V _{GS} = 11 V; V _{DS} = 0 V | - | - | 300 | nA |
| g _{fs} | forward transconductance | V _{DS} = 10 V; I _D = 15 A | - | 20.6 | - | S |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 V;$ $I_D = 10.5 A$ | - | 0.055 | - | Ω |

Table 7. RF characteristics

Test signal: 2-carrier W-CDMA; PAR = 7.5 dB at 0.01 % probability on the CCDF; 3GPP test model 1; 1-64 DPCH; f_1 = 1807.5 MHz; f_2 = 1812.5 MHz; f_3 = 1872.5 MHz; f_4 = 1877.5 MHz; RF performance at V_{DS} = 28 V; I_{Dq} = 3400 mA; T_{case} = 25 °C; unless otherwise specified; in a class-AB production test circuit, tested on straight lead device.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|--------------------|--------------------------------------|---------------------------|------|-----|-----|------|
| G_p | power gain | P _{L(AV)} = 95 W | 17.8 | 19 | - | dB |
| RLin | input return loss | P _{L(AV)} = 95 W | - | -12 | -6 | dB |
| η_{D} | drain efficiency | P _{L(AV)} = 95 W | 24 | 28 | - | % |
| ACPR _{5M} | adjacent channel power ratio (5 MHz) | P _{L(AV)} = 95 W | - | -33 | -28 | dBc |

7. Test information

7.1 Ruggedness in class-AB operation

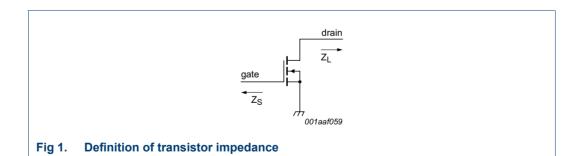
The BLF8G20LS-400PV and BLF8G20LS-400PGV are capable of withstanding a load mismatch corresponding to VSWR = 10 : 1 through all phases under the following conditions: V_{DS} = 28 V; I_{Dq} = 3300 mA; 2-carrier W-CDMA signal; P_{L} = 200 W; f_{c} = 1800 MHz; 5 MHz spacing, 46 % clipping.

7.2 Impedance information

Table 8. Typical impedance for the top-half of the push-pull package Measured load-pull data; $I_{Dq} = 1800 \text{ mA}$; $V_{DS} = 28 \text{ V}$; $T_{case} = 25 ^{\circ}\text{C}$, water cooled.

| f | Z _S [1] | Z _L [1] | | | |
|------------------------------|---------------------------------|--------------------|--|--|--|
| (MHz) | (Ω) | (Ω) | | | |
| BLF8G20LS-400PV (straight le | BLF8G20LS-400PV (straight lead) | | | | |
| 1800 | 4.1 – j4.66 | 4.1 – j4.5 | | | |
| 1840 | 5.2 – j3.6 | 4.4 – j4.4 | | | |
| 1880 | 4.6 – j1.45 | 4.85 – j4.25 | | | |
| 1930 | 2.8 – j0.3 | 4.5 – j4.3 | | | |
| 1960 | 2.1 – j0.5 | 5.5 – j3.5 | | | |
| 1990 | 1.56 – j0.6 | 5.5 – j3.4 | | | |
| BLF8G20LS-400PGV (gull-win | g) | | | | |
| 1800 | 3.7 – j7.6 | 4.2 – j6.8 | | | |
| 1840 | 4.34 – j6.1 | 4.4 – j6.7 | | | |
| 1880 | 4.75 – j5.2 | 4 – j6.4 | | | |
| 1930 | 3.17 – j3.4 | 4.6 – j6.5 | | | |
| 1960 | 2 – j3.05 | 5.8 – j5.5 | | | |
| 1990 | 2.5 – j2.6 | 5.8- j5.7 | | | |

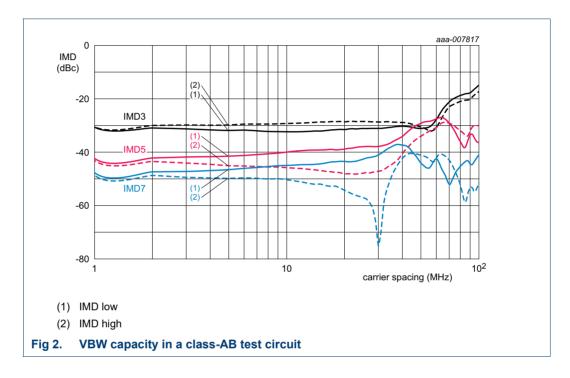
[1] Z_S and Z_L defined in Figure 1.



7.3 VBW in class-AB operation

The BLF8G20LS-400PV and BLF8G20LS-400PGV have a video bandwidth of 120 MHz (typical) when measured in a class-AB test circuit operating in the 1800 MHz to 1880 MHz frequency band for V_{DS} = 28 V and I_{Dq} = 3.3 A, where the VBW is defined as the location of the resonance in the base-band impedance measurement obtained using a low-frequency probe.

The VBW measurement based on the 2-tone IMD test as a function of carrier spacing is shown below.



7.4 Test circuit

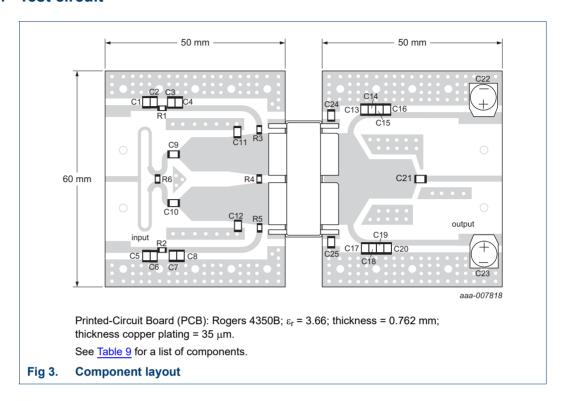


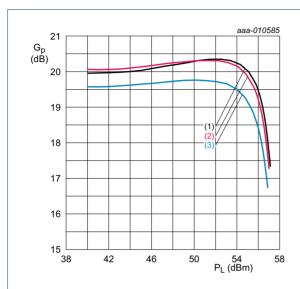
Table 9. List of components

See Figure 3 for component layout.

| Component | Description | Value | Remarks | |
|-----------------------------------|-----------------------------------|---------------|------------------|--|
| C1, C5, C16, C20 | multilayer ceramic chip capacitor | 10 μF, 50 V | Murata, SMD 2220 | |
| C2, C6, C15, C19, C24, C25 | multilayer ceramic chip capacitor | 4.7 μF, 50 V | Murata | |
| C3, C7, C14, C18 | multilayer ceramic chip capacitor | 1 nF | ATC100B | |
| C4, C8, C9, C10, C13, C17, C21 | multilayer ceramic chip capacitor | 24 pF | ATC100B | |
| C11, C12 | multilayer ceramic chip capacitor | 100 pF | ATC100B | |
| C22, C23 | electrolytic capacitor | 2200 μF, 63 V | | |
| R1, R2 | resistor | 10 Ω | SMD 1206 | |
| R3, R5 | resistor | 5.1 Ω | SMD 1206 | |
| R4 | resistor | 33 Ω | SMD 1206 | |
| R6 | resistor | 100 Ω | SMD 1206 | |

7.5 Graphical data

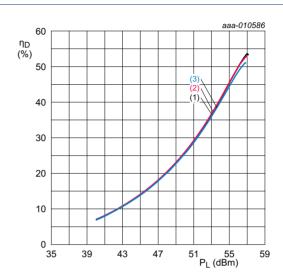
7.5.1 Pulsed CW



 V_{DS} = 28 V; I_{Dq} = 3400 mA; t_p = 100 $\mu s; \, \delta$ = 10 %.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 4. Power gain as a function of output power; typical values

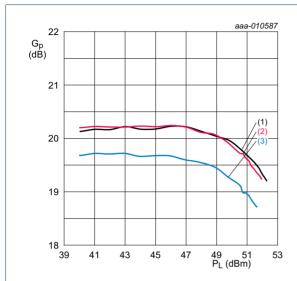


 V_{DS} = 28 V; I_{Dq} = 3400 mA; t_p = 100 μ s; δ = 10 %.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 5. Drain efficiency as a function of output power; typical values

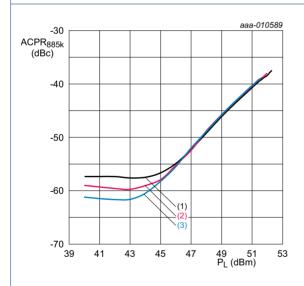
7.5.2 IS-95



 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

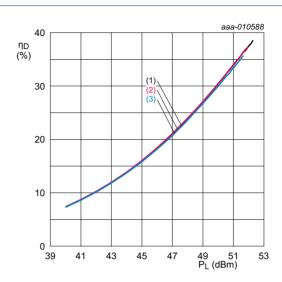
Fig 6. Power gain as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

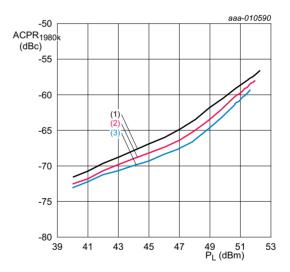
Fig 8. Adjacent channel power ratio (885 kHz) as a function of output power; typical values



 $V_{DS} = 28 \text{ V}$; $I_{Da} = 3400 \text{ mA}$.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 7. Drain efficiency as a function of output power; typical values



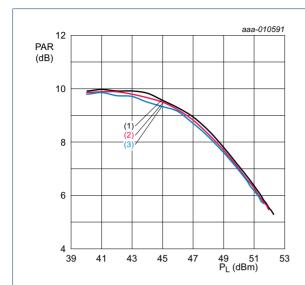
 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 9. Adjacent channel power ratio (1980 kHz) as a function of output power; typical values

BLF8G20LS-400P(G)V

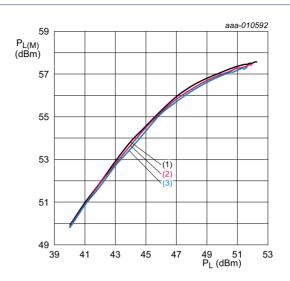
Power LDMOS transistor



 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 10. Peak-to-average ratio as a function of output power; typical values

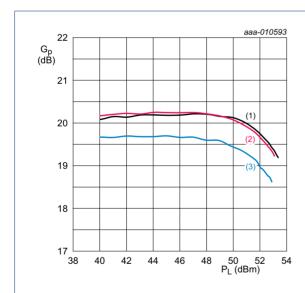


 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 11. Peak output power as a function of output power; typical values

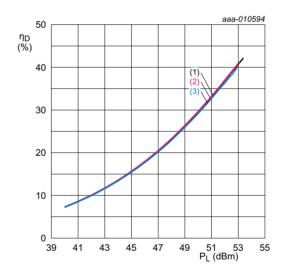
7.5.3 1-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 3400 mA.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 12. Power gain as a function of output power; typical values



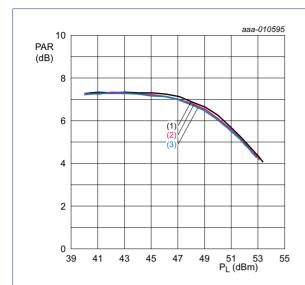
 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 13. Drain efficiency as a function of output power; typical values

BLF8G20LS-400P(G)V

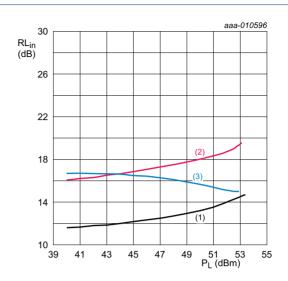
Power LDMOS transistor



 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 14. Peak-to-average ratio as a function of output power; typical values

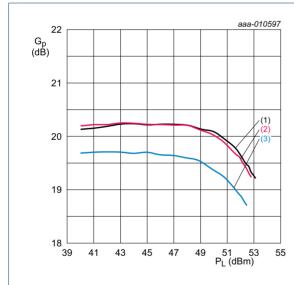


 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 15. Input return loss as a function of output power; typical values

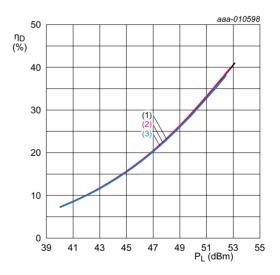
7.5.4 2-Carrier W-CDMA



 V_{DS} = 28 V; I_{Dq} = 3400 mA.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

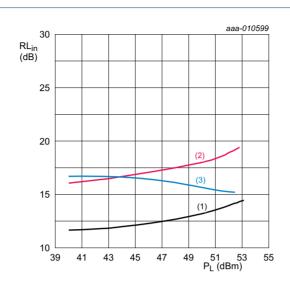
Fig 16. Power gain as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 3400 mA.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

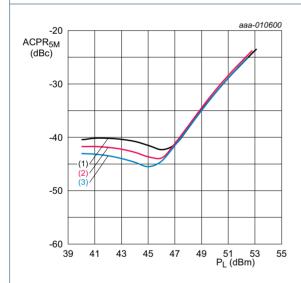
Fig 17. Drain efficiency as a function of output power; typical values



 $V_{DS} = 28 \text{ V}; I_{Dq} = 3400 \text{ mA}.$

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

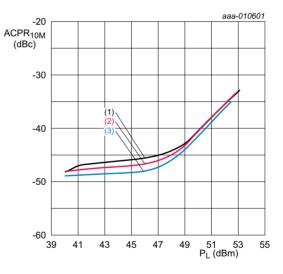
Fig 18. Input return loss as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 3400 mA.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 19. Adjacent channel power ratio (5 MHz) as a function of output power; typical values



 V_{DS} = 28 V; I_{Dq} = 3400 mA.

- (1) f = 1805 MHz
- (2) f = 1840 MHz
- (3) f = 1880 MHz

Fig 20. Adjacent channel power ratio (10 MHz) as a function of output power; typical values

8. Package outline

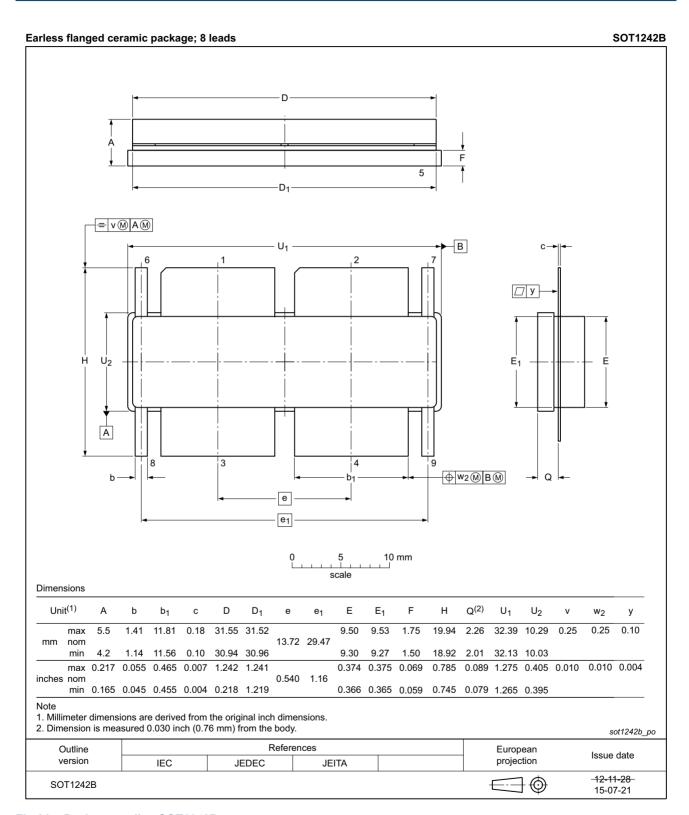


Fig 21. Package outline SOT1242B

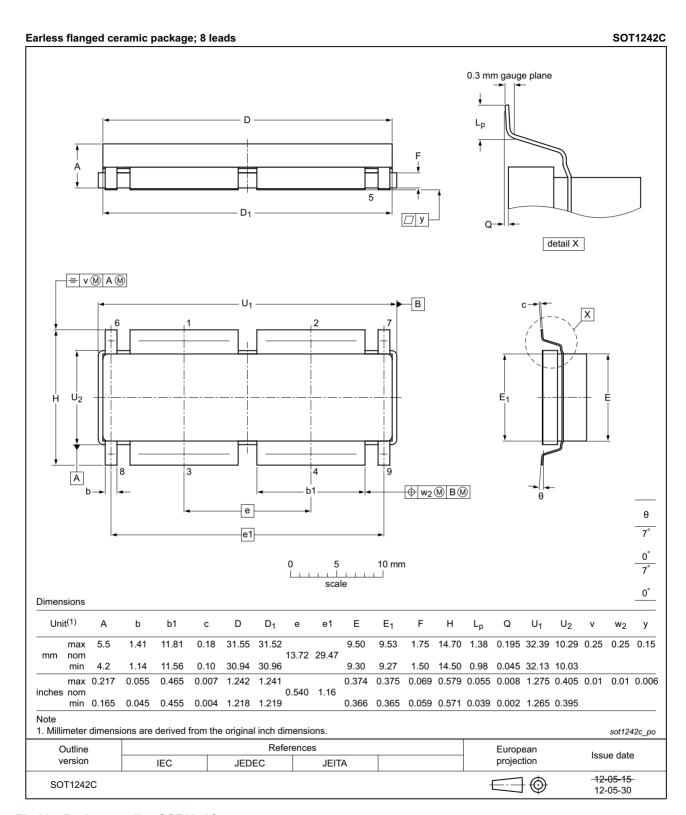


Fig 22. Package outline SOT1242C

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

10. Abbreviations

Table 10. Abbreviations

| Acronym | Description | |
|---------|--|--|
| 3GPP | 3rd Generation Partnership Project | |
| CCDF | Complementary Cumulative Distribution Function | |
| CW | Continuous Wave | |
| DPCH | Dedicated Physical Channel | |
| ESD | ElectroStatic Discharge | |
| IMD | InterModulation Distortion | |
| IS-95 | Interim Standard 95 | |
| LDMOS | Laterally Diffused Metal Oxide Semiconductor | |
| MTF | Median Time to Failure | |
| PAR | Peak-to-Average Ratio | |
| SMD | Surface Mounted Device | |
| VSWR | Voltage Standing Wave Ratio | |
| W-CDMA | Wideband Code Division Multiple Access | |

11. Revision history

Table 11. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------------------------|--|--------------------------|-----------------|-----------------------------------|
| BLF8G20LS-400PV_LS-400PGV#5 | 20150901 | Product data sheet | | BLF8G20LS-400PV _LS-400PGV v.4 |
| Modifications: | The format of this document has been redesigned to comply with the new identity guidelines of Ampleon. | | | |
| | Legal texts | have been adapted to the | new company nan | ne where appropriate. |
| BLF8G20LS-400PV_LS-400PGV v.4 | 20150728 | Product data sheet | - | BLF8G20LS-400PV _LS-400PGV v.3 |
| BLF8G20LS-400PV_LS-400PGV v.3 | 20140603 | Product data sheet | - | BLF8G20LS-400PV _LS-400PGV v.2 |
| BLF8G20LS-400PV_LS-400PGV v.2 | 20130625 | Product data sheet | - | BLF8G20LS-400PV _LS-400PGV v.1 |
| BLF8G20LS-400PV_LS-400PGV v.1 | 20130606 | Preliminary data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
| Product [short] data sheet | Production | This document contains the product specification. |

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
- The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL https://www.ampleon.com.

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